



TET ESTEL AS
ESTONIA

**June
2013**

**Series
D271-500
D271-500X**

**Rectifier Stud-Mounted
Diodes
Type D271-500,
D271-500X**

Designed for rectifiers and industrial applications.

Maximum mean forward current	I _{FAV}	500 A						
Maximum repetitive peak reverse voltage	U _{RRM}	1000 ÷ 1800 V						
Reverse recovery time	trr (typ)	25 µs						
U _{RRM} , V	1000	1100	1200	1300	1400	1500	1600	1800
Voltage code	10	11	12	13	14	15	16	18
Tvj, °C	- 60 ÷ 175							

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	D271-500 D271-500X	Conditions	
I _{FAV}	Mean forward current	A	500 800	Tc=120 °C, Tc=70 °C, 180° half-sine wave, 50 Hz	
I _{FRMS}	RMS forward current	A	785	Tc=120°C	
I _{FSM}	Surge forward current	kA	13 14	Tvj=175°C Tvj= 25°C	tp=10 ms
I ² t	Limiting load integral	kA ² s	845 980	Tvj=175°C Tvj= 25°C	UR=0
U _{RRM}	Repetitive peak reverse voltage	V	1000÷1800	Tj min≤Tvj≤TjM 180° half-sine wave, 50 Hz	
U _{RSR}	Non-repetitive peak reverse voltage	V	1100÷1900	Tj min≤Tvj≤TjM 180° half-sine wave tp=10 ms, Single pulse	
T _{stg}	Storage temperature	°C	-60÷80		
Tvj	Junction temperature	°C	-60÷175		

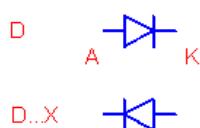
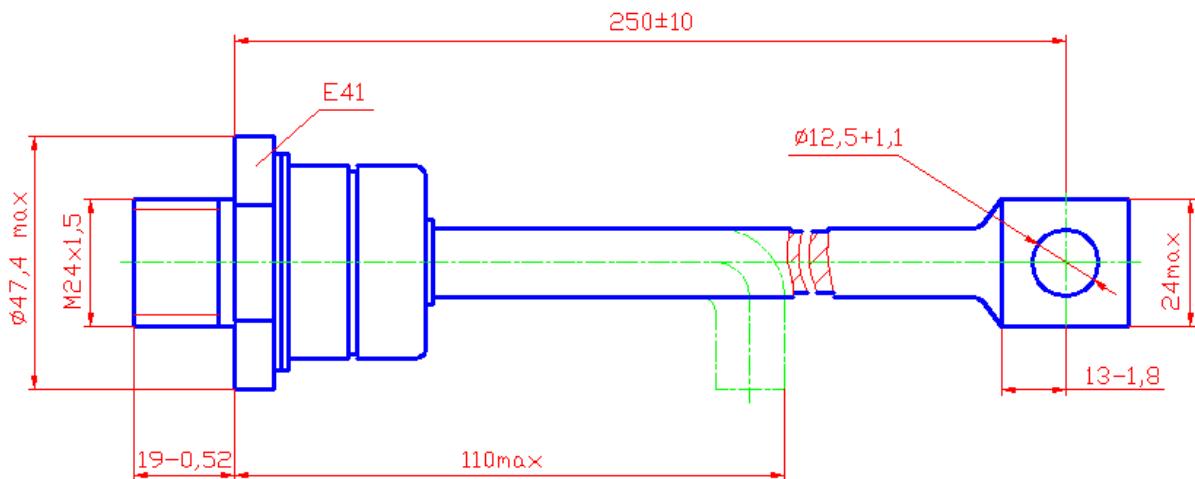
CHARACTERISTICS

U _{FM}	Peak forward voltage	V	1,5	Tvj=25°C, I _{FM} =3,14 I _{FAV}
U _{F(TO)}	Threshold voltage	V	0,85	Tvj=175°C
R _T	Forward slope resistance	mΩ	0,4	1,57 I _{FAV} < I _F <4,71 I _{FAV}
I _{RRM}	Repetitive peak reverse current	mA	50	Tvj=175°C, UR= U _{RRM}

CHARACTERISTICS				
Symbols and parameters		Units	D271-500 D271-500X	Conditions
Qrr	Recovered charge (typ)	µC	1500	Tvj=175°C, If=500A, Ur=100V dir / dt = 10A/µs
trr	Reverse recovery time (typ)	µS	25	
Irrm	Peak reverse recovery current (typ)	A	120	
Rthjc	Thermal resistance junction to case	°C/W	0,08	Direct current

ORDERING					
	D	271	500	X	16
	1	2	3	4	5

1. Diode
2. Design version
3. Mean forward current, A
4. Reverse polarity (cathode stud mounted), without X-normal polarity
5. Voltage code (16 = 1600 V)



Tightening torque: 40 ÷ 60 Nm
 Weight : 480 grams